

N-Channel Advanced Power MOSFET



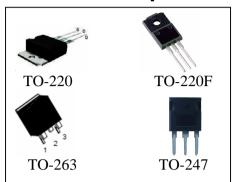
Features

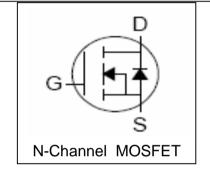
- 60V/120A, $R_{DS (ON)} = 6m\Omega$ (Type) $V_{GS} = 10V$ $I_{DS} = 40A$
- Ultra Low On-Resistance
- Exceptional dv/dt capability
- Fast Switching and Fully Avalanche Rated
- 100% avalanche tested
- 175°C Operating Temperature
- Lead Free and Green Available

Applications

- Switching Application Systems
- Inverter Systems

Pin Description





Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit						
Common Ratin	gs (T _A =25°C Unless Otherwise Noted)								
V_{DSS}	Drain-Source Voltage	60							
V_{GSS}	Gate-Source Voltage		±25	V					
TJ	Maximum Junction Temperature		175	°C					
T _{STG}	Storage Temperature Range	Storage Temperature Range							
I _S	Diode Continuous Forward Current	Diode Continuous Forward Current T _C =25°C							
Mounted on La	rge Heat Sink								
I _{DP}	300µs Pulse Drain Current Tested	300µs Pulse Drain Current Tested T _C =25°C							
I _D	Continuous Drain Current	T _C =25°C	120 ^①	Α					
.0	Continuous Brain Current	T _C =100°C	90	Α					
Ь	Maximum Dawar Dissination	T _C =25°C	200	١٨/					
P_D	Maximum Power Dissipation	T _C =100°C	150	W					
$R_{ heta JC}$	Thermal Resistance-Junction to Case	0.8	°C/W						
Drain-Source A	valanche Ratings								
E _{AS}	Avalanche Energy, Single Pulsed	·							



Electrical Characteristics (T_A=25°C Unless Otherwise Noted)

C: make al	Dozemster	Test Condition		RU6099		
Symbol	Parameter	rest Condition	Min.	Тур.	Max.	Unit
Static Cha	aracteristics	•				
BV _{DSS}	Drain-Source Breakdown Voltage	V_{GS} =0V, I_{DS} =250 μ A	60			V
	Zero Gate Voltage Drain Current	V _{DS} = 60V, V _{GS} =0V			1	
I _{DSS}	Zero Gate Voltage Drain Current	T _J =85°C			30	μΑ
V _{GS(th)}	Gate Threshold Voltage	$V_{DS}=V_{GS}$, $I_{DS}=250\mu A$	2	3	4	V
I _{GSS}	Gate Leakage Current	V _{GS} =±25V, V _{DS} =0V			±100	nA
R _{DS(ON)} ②	Drain-Source On-state Resistance	V _{GS} = 10V, I _{DS} =40A		6.0	7.0	mΩ
Diode Cha	aracteristics					
V _{SD}	Diode Forward Voltage	I _{SD} =20 A, V _{GS} =0V		0.83	1.1	V
trr	Reverse Recovery Time	Isb=40A, dlsb/dt=100A/μs		50		ns
Qrr	Reverse Recovery Charge					
Dynamic	Characteristics (3)					
R_G	Gate Resistance	V_{GS} =0V, V_{DS} =0V, F =1MHz		1.3		Ω
C _{iss}	Input Capacitance	Vgs=0V,		3000		
C _{oss}	Output Capacitance	V _{DS} = 30V,		430		pF
C_{rss}	Reverse Transfer Capacitance	Frequency=1.0MHz		240		
$t_{d(ON)}$	Turn-on Delay Time			14	27	
t _r	Turn-on Rise Time	Vdd=30V, Rl=30Ω, Ids= 1A, Vgen= 10V,		17	31	ns
$t_{\text{d(OFF)}}$	Turn-off Delay Time	$R_{G}=8\Omega$		40	68	
t_f	Turn-off Fall Time			62	95	
Gate Cha	rge Characteristics					
Q_g	Total Gate Charge			72	105	
Q_{gs}	Gate-Source Charge	Vps=30V, Vgs= 10V, lps=40A		13		nC
Q_{gd}	Gate-Drain Charge			24		

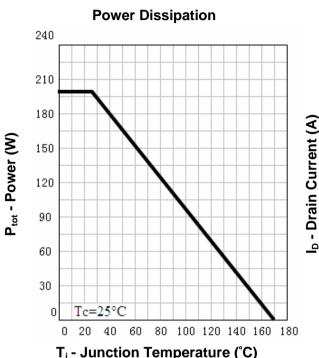
Notes: ①Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 75A.

②Pulse test ; Pulse width≤300μs, duty cycle≤2%.

③Guaranteed by design, not subject to production testing.



Typical Characteristics



120 105 90 75 60 45 30 15 0 20 40 60 80 100 120 140 160 180

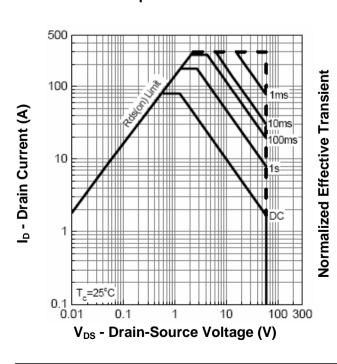
Drain Current

135

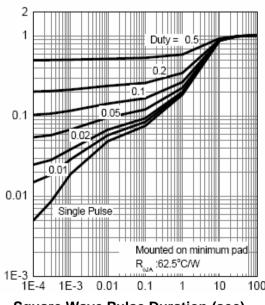
T_i - Junction Temperature (°C)

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Safe Operation Area



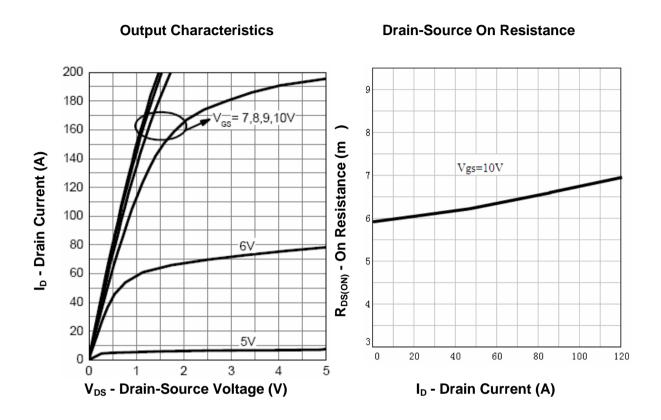
Thermal Transient Impedance



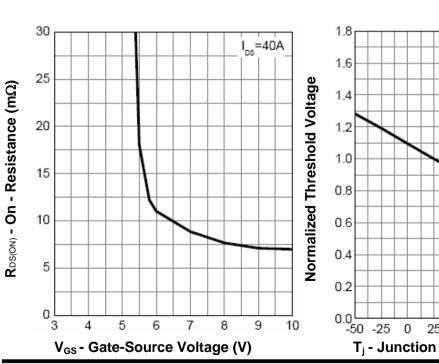
Square Wave Pulse Duration (sec)



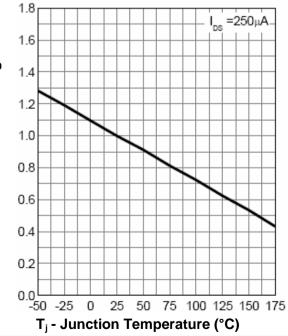
Typical Characteristics



Drain-Source On Resistance



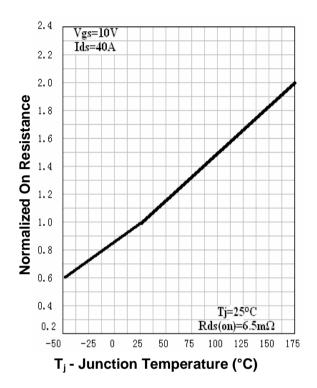
Gate Threshold Voltage



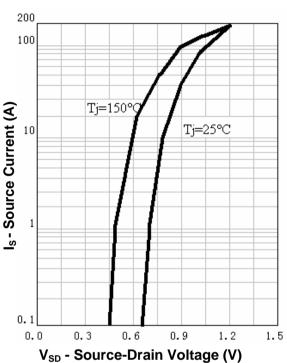


Typical Characteristics

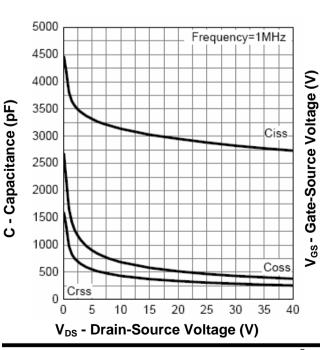
Drain-Source On Resistance



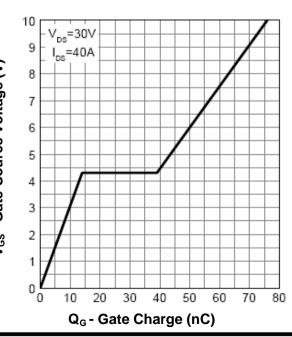
Source-Drain Diode Forward



Capacitance

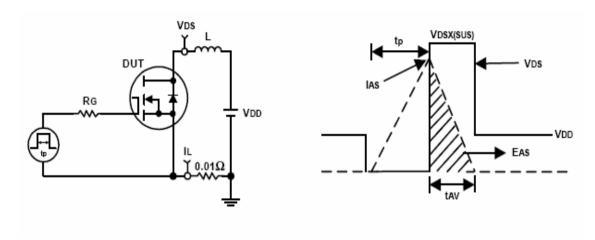


Gate Charge

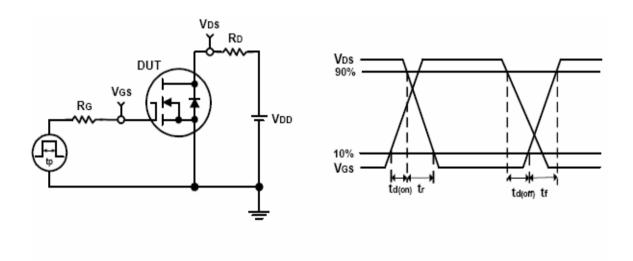




Avalanche Test Circuit and Waveforms



Switching Time Test Circuit and Waveforms





Ordering and Marking Information

RU6099

Package (Available)

R: TO-220; S: TO-263; P: TO-220F

Operating Temperature Range

C: -55 to 175 °C

Assembly Material

G: Green & Lead Free

Packaging

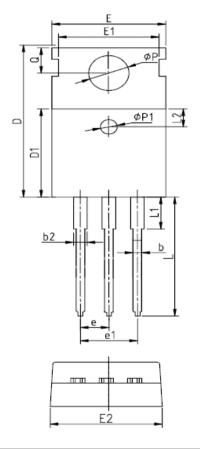
T: TUBE

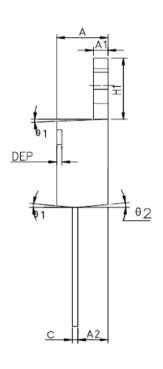
TR: Tape & Reel



Package Information

TO-220FB-3L



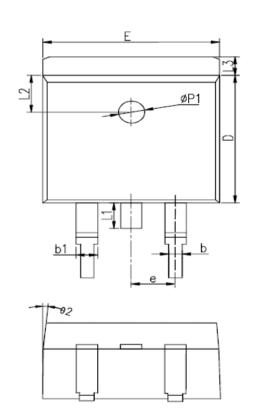


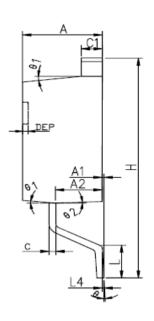
SYMBOL		MM			INCH		CVA (DO)		MM			INCH		
STMBOL	MIN	MIN NOM MAX MIN NOM MAX SYMBO	SYMBOL	MIN	NOM	MAX	MIN	NOM	MAX					
A	4.40	4.57	4.70	0.173	0.180	0.185	Øp1	1.40	1.50	1.60	0.055	0.059	0.063	
A1	1.27	1.30	1.33	0.050	0.051	0.052	e	2.54BSC				0.1BSC		
A2	2.35	2.40	2.50	0.093	0.094	0.098	e1	5.08BSC			0.2BSC			
b	0.77	-	0.90	0.030	-	0.035	H1	6.40	6.50	6.60	0.252	0.256	0.260	
b2	1.23	-	1.36	0.048	-	0.054	L	12.75	-	13.17	0.502	-	0.519	
С	0.48	0.50	0.52	0.019	0.020	0.021	L1	-	-	3.95	-	-	0.156	
D	15.40	15.60	15.80	0.606	0.614	0.622	L2		2.50REF	Ī	0.098REF.			
D1	9.00	9.10	9.20	0.354	0.358	0.362	Øр	3.57	3.60	3.63	0.141	0.142	0.143	
DEP	0.05	0.10	0.20	0.002	0.004	0.008	Q	2.73	2.80	2.87	0.107	0.110	0.113	
Е	9.70	9.90	10.10	0.382	0.389	0.398	θ 1	5°	7°	9°	5°	7°	9°	
E1	-	8.70	-	-	0.343	-	θ 2	1°	3°	5°	1°	3°	5°	
E2	9.80	10.00	10.20	0.386	0.394	0.401								

ALL DIMENSIONS REFER TO JEDEC STANDARD DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS



TO-263-2L



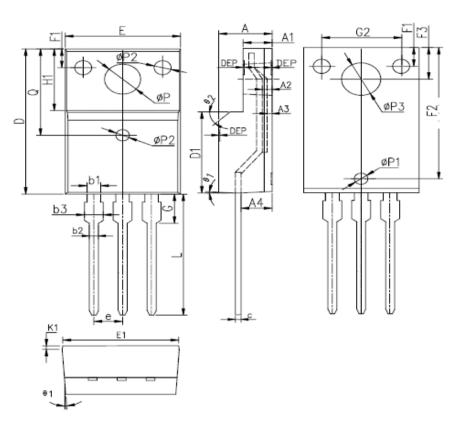


SYMBOL		MM			INCH		MM					INCH		
SYMBOL	MIN	NOM	MAX	MIN	NOM	MAX	SYMBOL	MIN	NOM	MAX	MIN	NOM	MAX	
A	4.40	4.57	4.70	0.173	0.180	0.185	L	2.00	2.30	2.60	0.079	0.090	0.102	
A1	0	0.10	0.25	0	0.004	0.010	L3	1.17	1.27	1.40	0.046	0.050	0.055	
A2	2.59	2.69	2.79	0.102	0.106	0.110	L1	-	-	1.70	-	-	0.067	
b	0.77	-	0.90	0.030	-	0.035	L4	0.25BSC				0.01BSC		
b1	1.23	-	1.36	0.048	-	0.052	L2	2.50REF.			0.098REF.			
c	0.34	-	0.47	0.013	-	0.019	θ	0°	-	8°	0°	-	8°	
C1	1.22	-	1.32	0.048	-	0.052	θ 1	5°	7°	9°	5°	7°	9°	
D	8.60	8.70	8.80	0.338	0.343	0.346	θ 2	1°	3°	5°	1°	3°	5°	
Е	10.00	10.16	10.26	0.394	0.4	0.404	DEP	0.05	0.10	0.20	0.002	0.004	0.008	
e		2.54BSC	2.54BSC 0.1BSC			Øp1	1.40	1.50	1.60	0.055	0.059	0.063		
Н	14.70	15.10	15.50	0.579	0.594	0.610								

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TO-220F-3L



SYMBOL		MM			INCH		ara abor	MM				INCH	
SIMBOL	MIN	NOM	MAX	MIN	NOM	MAX	SYMBOL	MIN	NOM	MAX	MIN	NOM	MAX
Е	9.96	10.16	10.36	0.392	0.400	0.408	Øp3	-	3.450	-	-	0.136	-
A	4.50	4.70	4.90	0.177	0.185	0.193	θ 1	5°	7°	9°	5°	7°	9°
A1	2.34	2.54	2.74	0.092	0.100	0.108	θ 2	-	45°	-	-	45°	-
A2	0.95	1.05	1.15	0.037	0.041	0.045	DEP	0.05	0.10	0.15	0.002	0.004	0.006
A3	0.42	0.52	0.62	0.017	0.020	0.024	F1	1.90	2.00	2.10	0.075	0.079	0.083
A4	2.65	2.75	2.85	0.104	0.108	0.112	F2	13.61	13.81	14.01	0.536	0.544	0.552
c	-	0.50	-	-	0.020	-	F3	3.20	3.30	3.40	0.126	0.130	0.134
D	15.67	15.87	16.07	0.617	0.625	0.633	G	3.25	3.45	3.65	0.128	0.136	0.144
Q	8.80	9.00	9.20	0.346	0.354	0.362	G1	5.90	6.00	6.10	0.232	0.236	0.240
H1	6.48	6.68	6.88	0.255	0.263	0.271	G2	6.90	7.00	7.10	0.272	0.276	0.280
e		2.54BSC			0.1BSC		b1	1.17	1.20	1.24	0.046	0.047	0.048
Øp	-	3.183	-	-	0.125	-	b2	0.77	0.8	0.85	0.030	0.031	0.033
L	12.78	12.98	13.18	0.503	0.511	0.519	b3	1.10	1.30	1.50	0.043	0.051	0.059
D1	8.99	9.19	9.39	0.354	0.362	0.370	E1	9.8	10.00	10.20	0.386	0.394	0.412
Øp1	1.40	1.50	1.60	0.055	0.059	0.063	K1	0.75	0.8	0.85	0.030	0.031	0.033
Øp2	1.15	1.20	1.25	0.045	0.047	0.049							

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